NSN 5961-00-836-8519

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View Online at https://aerobasegroup.com/nsn/5961-00-836-8519

Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.370 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 35.0
breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 5.2 breakdown voltage, emitter-to-base
collector open
Current Rating Per Characteristic:
Between 600.00 milliamperes source cutoff current and 1.00 amperes source cutoff current
Power Rating Per Characteristic:
600.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Nuclear Hardness Critical Feature:
Hardened
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0